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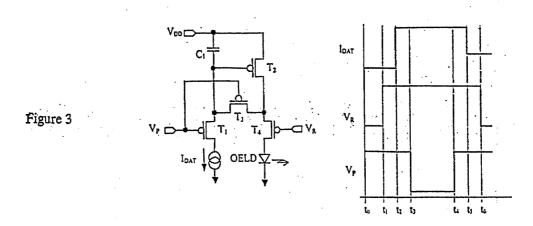
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- (71) Applicant: SEIKO EPSON CORPORATION Shinjuku-ku Tokyo (JP)
- (72) Inventor: Tam, Simon
  Cambridge CB2 1SJ (GB)
- (74) Representative: Sturt, Clifford Mark et al Miller Sturt Kenyon 9 John Street London WC1N 2ES (GB)

### (54) Current sampling circuit for organic electroluminescent display

(57) A driver circuit operating in stages that comprise a programming stage and a reproduction stage, the circuit comprising: a plurality current paths each of which passes through the circuit, a current driven element, a transistor connected so as operatively to control the current supplied to the said element, a capacitor connected for storing an operating voltage of the transistor during the programming stage, and switching means which control the current paths, the arrangement

being such that one of the current paths does not include the said element. No current is applied to the current driven element by the current controlling transistor during the programming stage and thus the overall power consumption is reduced. Furthermore, the circuit can be operated from a normal supply voltage rather than requiring a high bias voltage. During the programming stage, the circuit uses a current sink rather than a current source. Preferably, the current driven element is an electroluminescent element.



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[0001] The present invention relates, inter alia, to a driver circuit. One particular application of such a driver circuit is for driving a pixel of an organic electroluminescent device.

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[0002] An organic electro-luminescent (OEL) element comprises a light emitting material layer sandwiched between an anode layer and a cathode layer. Electrically, this element operates like a diode. Optically, it emits light when forward biased and the intensity of the emission increases with the forward bias current. It is possible to construct a display panel with a matrix of OEL elements fabricated on a transparent substrate and with at least one of the electrode layers being transparent. One can also integrate the driving circuit on the same panel by using low temperature polysilicon thin film transistor (TFT) technology.

[0003] In a basic analog driving scheme for an active matrix OEL display, a minimum of two transistors are required per pixel (Figure 1): T1 is for addressing the pixel and T2 is for converting the data voltage signal into current which drives the OEL element at a designated brightness; The data signal is stored by the storage capacitor C<sub>storage</sub> when the pixel is not addressed. Although p-channel TFTs are shown in the figures, the same principle can also be applied for a circuit with nchannel TFTs.

[0004] There are problems associated with TFT analog circuits and OEL elements do not act like perfect diodes. The light emitting material does, however, have relatively uniform characteristics. Due to the nature of the TFT fabrication technique, spatial variation of the TFT characteristics exists over the entire panel. One of the most important considerations in a TFT analog circuit is the variation of threshold voltage,  $\Delta V_T$ , from device to device. The effect of such variation in an OEL display, exacerbated by the non perfect diode behaviour, is the non-uniform pixel brightness over the display panel, which seriously affects the image quality. Therefore, a built-in circuit for compensating a dispersion of transistor characteristics is required.

[0005] A circuit shown in figure 2 is proposed as one of built-in for compensating a variation of transistor characteristics. In this circuit, T<sub>1</sub> is for addressing the pixel. T<sub>2</sub> operates as an analog current control to provide the driving current. T<sub>3</sub> connects between the drain and gate of T<sub>2</sub> and toggles T<sub>2</sub> to be either a diode or in saturation. T<sub>4</sub> acts as a switch. Either T<sub>1</sub> or T<sub>4</sub> can be ON at any one time. Initially,  $T_1$  and  $T_3$  are OFF, and  $T_4$  is ON. When  $T_4$  is OFF,  $T_1$  and  $T_3$  are ON, and a current of known value is allowed to flow into the OEL element, through T2. This is the programming stage because the threshold voltage of T2 is measured with T2 operating as a diode (with T<sub>3</sub> turned ON) while the programming current is allowed to flow through T<sub>1</sub>, through T<sub>2</sub> and into the OEL element. T<sub>3</sub> shorts the drain and gate of T<sub>2</sub> and turns T2 in to a diode. The detected threshold voltage of

T2 is stored by the capacitor C1 connected between the gate and source terminals of T2 when T3 and T1 are switched OFF. Then T<sub>4</sub> is turned ON, the current is now provided by V<sub>DD</sub>. If the slope of the output characteristics were flat, the reproduced current would be the same as the programmed current for any threshold voltage of T<sub>2</sub> detected. By turning ON T<sub>4</sub>, the drain-source voltage of T<sub>2</sub> is pulled up, so a flat output characteristic will keep the reproduced current the same as the programmed current. Note that  $\Delta V_{T2}$  shown in figure 2 is imaginary, not real.

[0006] A constant current is provided, in theory, during the active programming stage, which is t<sub>2</sub> to t<sub>5</sub> in the timing diagram shown in figure 2. The reproduction stage starts at t<sub>6</sub>.

[0007] The circuit of figure 2 is advantageous but there is an on-going desire to reduce power consumption. In particular, implementation of the current-source in the circuit of figure 2 requires a bias voltage ( $V_{BIAS}$ ) in addition to the supply voltage (V<sub>DD</sub>). Although the supply voltage (VDD) could be increased to cover the required bias voltage (VBIAS) - which would have the advantage of reducing the component count, there is still an overall increase in system power consumption to program with any value of data current (IDAT).

[0008] Attention is, by the present invention, drawn to the fact that all currents passing through the circuit of figure 2 pass through the OEL element. The significance of this to the present invention will be apparent from the description given hereinafter.

[0009] According to a first aspect of the present invention there is provided a driver circuit operating in stages that comprise a programming stage and a reproduction stage, the circuit comprising: a plurality of current paths each of which passes through the circuit, a current driven element, a transistor connected so as operatively to control the current supplied to the said element, a capacitor connected for storing an operating voltage of the transistor during the programming stage, and switching means which control the current paths, the arrangement being such that one of the current paths does not include the said element.

[0010] According to a second aspect of the present invention there is provided a driver circuit for driving a pixel of an electroluminescent device, the pixel including an electroluminescent element and the circuit comprising; a transistor connected'so as operatively to control the current supplied to the electroluminescent element, a capacitor connected for storing an operating voltage of the transistor during a programming stage, a first switching means connected so as to establish when operative a current path through the transistor during the programming stage, and a second switching means connected so as to establish when operative a current path through the transistor and the electroluminescent element during a reproduction stage, wherein the first switching means is connected such that the current path during the programming stage does not pass through the electroluminescent element.

[0011] According to a third aspect of the present invention there is provided a driver circuit for driving a pixel of an electroluminescent device, the pixel including an electroluminescent element and the circuit comprising; a transistor connected so as operatively to control the current supplied to the electroluminescent element, a capacitor connected for storing an operating voltage of the transistor during a programming stage, a first switching means connected so as to establish when operative a current path through the transistor during the programming stage, a second switching means connected so as to establish when operative a current path through the transistor and the electroluminescent element during a reproduction stage, and a current sink, the first switching means being connected such that the current path during the programming stage is through the transistor to the current sink.

**[0012]** According to a fourth aspect of the present invention there is provided a method of controlling the current supply to an electroluminescent element comprising the steps of providing a current path during a programming stage which path does not pass through the electroluminescent element and of providing a current path during a reproduction stage which path does pass through the electroluminescent element.

**[0013]** According to a fifth aspect of the present invention there is provided a method of controlling the current supply to an electroluminescent element comprising the steps of providing a current path during a programming stage which path connects to a current sink and of providing a current path during a reproduction stage which path passes through the electroluminescent element.

**[0014]** According to a sixth aspect of the present invention there is provided an electroluminescent display device comprising one or more driver circuits according to any of the first to third aspects of the present invention.

**[0015]** According to a seventh aspect of the present invention there is provided an electronic apparatus incorporating an electroluminescent display device according to the sixth aspect of the present invention.

**[0016]** According to an eight aspect of the present invention there is provided a circuit comprising a current driven element, the circuit providing a first current path including the current driven element and a second current path not including the current driven element.

**[0017]** According to a nineth aspect of the present invention there is provided a circuit comprising a current driven element, the circuit providing a first current path flowing a current through the current driven element, and a second current path not flowing current through the current driven element.

[0018] According to a tenth aspect of the present invention there is provided a method for driving a circuit comprising a current driven element and a transistor that controls a current supplied to the current driven element, comprising a step of determining a gate voltage of the

transistor based on a predetermined current.

[0019] It will be noted that according to the present invention no current is applied to the current driven element by the current controlling transistor during the programming stage. In accordance with the invention in an electroluminescent device a pixel driver circuit can be implemented without degrading the perceived image presented by the electroluminescent device. It has the benefit of reducing the overall power consumption compared with the prior art in which the same current is supplied to the OEL element during both the programming and the reproduction stage. Furthermore, the circuit can be operated from a normal supply voltage rather than requiring a high bias voltage as in the prior art. In effect, the present invention provides for separation of the programming and the reproduction current paths. This enables a number of advantages to be achieved. For example, if there is no current flow through the OEL element during the programming stage then the programming stage operates more quickly - since the arrangement avoids the slow down caused by the parasitic capacitance of the OEL element.

**[0020]** Embodiments of the present invention will now be described by way of further example only and with reference to the accompanying drawings, in which:-

Figure 1 shows a conventional OEL element pixel driver circuit using two transistors,

Figure 2 shows a known current programmed OEL element driver with threshold voltage compensation.

Figure 3 shows a pixel driver circuit according to a first embodiment of the present invention,

Figure 4 shows a pixel driver circuit according to a second embodiment of the present invention,

Figure 5 shows several pixels in a matrix display wherein each pixel uses the circuit of figure 4, Figure 6 is a schematic sectional view of a physical

implementation of an OEL element and pixel driver according to an embodiment of the present invention.

Figure 7 is a simplified plan view of an OEL display panel incorporating the present invention,

Figure 8 shows another embodiment of a pixel driver circuit according to the present invention,

Figure 9 shows another embodiment of a pixel driver circuit according to the present invention,

Figure 10 is a schematic view of a mobile personal computer incorporating a display device having a pixel driver according to the present invention,

Figure 11 is a schematic view of a mobile telephone incorporating a display device having a pixel driver according to the present invention.

Figure 12 is a schematic view of a digital camera incorporating a display device having a pixel driver according to the present invention,

Figure 13 illustrates the application of the driver circuit of the present invention to a magnetic RAM,

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Figure 14 illustrates the application of the driver circuit of the present invention to a magnetoresistive element.

Figure 15 illustrates the application of the driver circuit of the present invention to a capacitance sensor or a charge sensor,

Figure 16 illustrates the application of the driver circuit of the present invention to a night vision camera, and

Figure 17 is a brief outline of an alternative implementation of the circuit of figure 4.

[0021] A pixel driver circuit according to a first embodiment of the present invention is shown in figure 3. Transistor T2 operates as an analog current control to provide the driving current to the OEL element. Also, the storage capacitor C1 is connected between the gate and the source of transistor  $T_2$ . In the circuit of figure 2, a current source is operatively connected to the source of transistor T<sub>2</sub> by transistor T<sub>1</sub>, during the programming stage, and current is thus applied to the OEL element. In the embodiment of the present invention, transistor T<sub>1</sub> operatively connects transistor T<sub>2</sub> to a current sink during the programming stage. That is, according to the present invention, during the programming stage no current is supplied through transistor T2 to the OEL element. In the circuit of figure 3, the drain of transistor T<sub>2</sub> is connected to the source of transistor T1 via the source/drain path of transistor T3. The source of transistor  $T_1$  is connected to the gate of transistor  $T_2$  and the gates of transistors T<sub>1</sub> and T<sub>3</sub> are connected together. The programming voltage V<sub>P</sub> is applied to the gates of T<sub>1</sub> and T<sub>3</sub>. Transistor T<sub>4</sub>, which is switched off during the programming stage, connects the drain of  $T_2$  and the source of T3 to the OEL element. During the programming stage, transistor T<sub>1</sub> operatively connects transistor T2 to a current sink which is tied to ground or a reference voltage.

[0022] The circuit of figure 3 operates in the programming stage with T<sub>4</sub> switched off and T<sub>1</sub> and T<sub>3</sub> switched on. T<sub>3</sub> being switched on has the effect of making T<sub>2</sub> act as a diode and T<sub>1</sub> connects this diode to the data current sink. As a result, capacitor C<sub>1</sub> charges (or discharges, depending on the voltage stored during the previous frame). Capacitor C<sub>1</sub> charges to the gate/source voltage of transistor T2 and thus stores the voltage (VGS2, corresponding to the data current IDAT) which will control the current supply to the OEL element during the reproduction stage. At the end of the programming stage, T<sub>1</sub> and  $T_3$  are switched off. The voltage  $V_{GS2}$  is stored on C<sub>1</sub> for the remainder of the frame period. As will be readily apparent from the circuit diagram and this description, in accordance with the present invention there is no requirement for a bias voltage to provide a current source. That is, the supply voltage (V<sub>DD</sub>) in figure 3 is determined by T2 and by the OEL element and there is no requirement for a high voltage to power a current source. The maximum voltage required by the circuit is

thus significantly less than that required by the circuit of figure 2.

[0023] At the start of the programming stage, with T<sub>4</sub> switched off, it is found that the OEL element exhibits a parasitic capacitance which discharges through the device. The rate of charging of C<sub>1</sub> determines the time taken for the programming stage. In accordance with circuits embodying the present invention, the capacitance of C<sub>1</sub> can be relatively small and thus the charging can be very rapid. As a consequence, the period for which no current is applied to the OEL element by T<sub>2</sub> is very short compared with the whole frame. These factors, together with the persistence of vision of the human eye means that there is no perceptible degradation of a displayed image.

**[0024]** The off resistance of  $T_3$  can be important, because after  $C_1$  has been charged and  $T_3$  is switched off, the off resistance of  $T_3$  can affect the voltage across  $C_1$  for the rest of the frame period. Thus, the gate/source capacitance of  $T_3$  should preferably be small compared with  $C_4$ .

**[0025]** The reproduction voltage  $V_R$  is applied to the gate of transistor  $T_4$ . At the beginning of the reproduction stage, in the circuit of figure 3,  $T_4$  is switched on and  $T_1$  and  $T_3$  remain switched off. As a result,  $T_2$  acts as a current source with  $V_{GS2}$  biased by  $C_1$ , thus supplying current to the OEL element. At the end of the reproduction stage  $T_4$  is switched off,  $T_1$  and  $T_3$  remain switched off. This completes one cycle. The driving waveform is indicated in figure 3.

**[0026]** Figure 4 illustrates a second embodiment according to the present invention. The circuit of figure 4 differs from that of figure 3 in the connection of transistor  $T_3$ . In the circuit of figure 4.  $T_1$  is connected to  $C_1$  through the drain/source path of  $T_3$ . The circuit of figure 4 is preferred to that of figure 3 because  $T_3$  is not in the current path during the programming stage. Otherwise the operation and effects of the second embodiment are similar to those of the first embodiment.

**[0027]** Figure 5 is a circuit diagram showing a number of pixels in an active matrix display, with each pixel implemented in accordance with the circuit of figure 4. To simplify the illustration, a monochrome display device is shown. Since the circuit is of an active matrix, pixels on the same row are addressed at the same time. Transistor  $T_3$  is responsible for pixel addressing, so its source terminal is connected to the current data line shared by a column of pixels. Because of this the leakage current of  $T_3$  should be kept to a minimum. This can be ensured by using a multi-gate structure for  $T_1$ . In addition to a multi-gate structure, a lightly doped drain (LDD) structure can also reduce the leakage current.

**[0028]** Figure 6 is a schematic cross-sectional view of the physical implementation of the pixel driver circuit in an OEL element structure. In figure 6, numeral 132 indicates a hole injection layer, numeral 133 indicates an organic EL layer, and numeral 151 indicates a resist or separating structure. The switching thin-film transistor

121 and the n-channel type current-thin-film transistor 122 adopt the structure and the process ordinarily used for a low-temperature polysilicon thin-film transistor, such as are used for example in known thin-film transistor liquid crystal display devices such as a top-gate structure and a fabrication process wherein the maximum temperature is 600°C or less. However, other structures and processes are applicable.

**[0029]** The forward oriented organic EL display element 131 is formed by: the pixel electrode 115 formed of Al, the opposite electrode 116 formed of ITO, the hole injection layer 132, and the organic EL layer 133. In the forward oriented organic EL display element 131, the direction of current of the organic EL display device can be set from the opposite electrode 116 formed of ITO to the pixel electrode 115 formed of Al.

**[0030]** The hole injection layer 132 and the organic EL layer 133 may be formed using an ink-jet printing method, employing the resist 151 as a separating structure between the pixels. The opposite electrode 116 formed of ITO may be formed using a sputtering method. However, other methods may also be used for forming all of these components.

[0031] The typical layout of a full display panel employing the present invention is shown schematically in figure 7. The panel comprises an active matrix OEL element 200 with analogue current program pixels, an integrated TFT scanning driver 210 with level shifter, a flexible TAB tape 220, and an external analogue driver LSI 230 with an integrated RAM/controller. Of course, this is only one example of the possible panel arrangements in which the present invention can be used.

**[0032]** The structure of the organic EL display device is not limited to the one described here. Other structures are also applicable.

[0033] With reference for example to the circuit of figure 3, it will be appreciated that the invention provides a data current source - in this case for the OEL element. The circuit is readily extended so as to provide an amplified and/or multiple level (current) output. The principle of such a circuit can be understood with reference to figure 8. the circuit of figure 8 comprises the circuit of figure 3 with an additional drive transistor T<sub>5</sub> and an additional switching transistor  $\rm T_{\rm 6}$  added. The source of  $\rm T_{\rm 5}$ is connected to V<sub>DD</sub> and its gate receives the same drive voltage signal as is applied to the gate of transistor  $T_2$ . The drain of transistor T<sub>5</sub> is series connected to the drain of transistor T<sub>6</sub> and the source of T<sub>6</sub> is connected to the common point of connection of transistors T2, T3 and T<sub>4</sub>. The gate of transistor T<sub>6</sub> is connected to the gate of transistor T<sub>4</sub>. If it is assumed that the characteristic of transistor T2 is W/L and that the characteristic of transistor T<sub>5</sub> is selected to be (N-1)W/L then a current amplification of:-

$$I_{out} = I_{in} \times N$$

is achieved.  $I_{in}$  is the current which flows through the current sink, i.e.  $I_{DAT}$  in figures 3 and 4.  $I_{out}$  is the current which flows through the OEL element. Thus the circuit of figure 8 can be used to reduce the value of  $I_{DAT}$  compared with the circuit of figures 3 and 4, while maintaining the same current through the OEL element. Lowering the value of  $I_{DAT}$  has the advantage of enabling the operating speed of the circuit to be increased. Lowering the value of  $I_{DAT}$  also has the advantage of lowering the transmission loss experienced across a matrix of pixels, which is particularly important with respect to large scale display panels.

**[0034]** Of course, additional stages - each adding their own circuit of additional transistors  $T_5$  and  $T_6$  - can be added. With the switching transistors  $T_6$  series connected and each receiving its own gate drive signal - as shown in figure 9 (A,B etc) - different current values can be selected to pass through the OEL element, resulting in different intensities of light output.

**[0035]** Preferably the circuits shown in figures 3 to 9 are implemented using thin film transistor (TFT) technology, most preferably in polysilicon.

**[0036]** The present invention is particularly advantageous for use in small, mobile electronic products such as mobile phones, computers, CD players, DVD players and the like - although it is not limited thereto.

[0037] Several electronic apparatuses using the above organic electroluminescent display device will now be described.

#### <1: Mobile Computer>

**[0038]** An example in which the display device according to one of the above embodiments is applied to a mobile personal computer will now be described.

**[0039]** Figure 10 is an isometric view illustrating the configuration of this personal computer. In the drawing, the personal computer 1100 is provided with a body 1104 including a keyboard 1102 and a display unit 1106. The display unit 1106 is implemented using a display panel fabricated according to the present invention, as described above.

### <2: Portable Phone>

**[0040]** Next, an example in which the display device is applied to a display section of a portable phone will be described. Fig. 11 is an isometric view illustrating the configuration of the portable phone. In the drawing, the portable phone 1200 is provided with a plurality of operation keys 1202, an earpiece 1204, a mouthpiece 1206, and a display panel 100. This display panel 100 is implemented using a display panel fabricated according to the present invention, as described above.

#### <3: Digital Still Camera>

[0041] Next, a digital still camera using an OEL dis-

play device as a finder will be described. Fig. 12 is an isometric view illustrating the configuration of the digital still camera and the connection to external devices in brief.

[0042] Typical cameras sensitize films based on optical images from objects, whereas the digital still camera 1300 generates imaging signals from the optical image of an object by photoelectric conversion using, for example, a charge coupled device (CCD). The digital still camera 1300 is provided with an OEL element 100 at the back face of a case 1302 to perform display based on the imaging signals from the CCD. Thus, the display panel 100 functions as a finder for displaying the object. A photo acceptance unit 1304 including optical lenses and the CCD is provided at the front side (behind in the drawing) of the case 1302.

[0043] When a cameraman determines the object image displayed in the OEL element panel 100 and releases the shutter, the image signals from the CCD are transmitted and stored to memories in a circuit board 1308. In the digital still camera 1300, video signal output terminals 1312 and input/output terminals 1314 for data communication are provided on a side of the case 1302. As shown in the drawing, a television monitor 1430 and a personal computer 1440 are connected to the video signal terminals 1312 and the input/output terminals 1314, respectively, if necessary. The imaging signals stored in the memories of the circuit board 1308 are output to the television monitor 1430 and the personal computer 1440, by a given operation.

**[0044]** Examples of electronic apparatuses, other than the personal computer shown in Fig. 10, the portable phone shown in Fig. 11, and the digital still camera shown in Fig. 12, include OEL element television sets, view-finder-type and monitoring-type video tape recorders, car navigation systems, pagers, electronic notebooks, portable calculators, word processors, workstations, TV telephones, point-of-sales system (POS) terminals, and devices provided with touch panels. Of course, the above OEL device can be applied to display sections of these electronic apparatuses.

**[0045]** The driver circuit of the present invention can be disposed not only in a pixel of a display unit but also in a driver disposed outside a display unit.

**[0046]** In the above, the driver circuit of the present invention has been described with reference to various display devices. The applications of the driver circuit of the present invention are much broader than just display devices and include, for example, its use with a magnetoresistive RAM, a capacitance sensor, a charge sensor, a DNA sensor, a night vision camera and many other devices.

**[0047]** Figure 13 illustrates the application of the driver circuit of the present invention to a magnetic RAM. In figure 13 a magnetic head is indicated by the reference MH.

[0048] Figure 14 illustrates the application of the driver circuit of the present invention to a magnetoresistive

element. In figure 14 a magnetic head is indicated by the reference MH. and a magnetic resistor is indicated by the reference MR.

**[0049]** Figure 15 illustrates the application of the driver circuit of the present invention to a capacitance sensor or a charge sensor. In figure 15 a sense capacitor is indicated by the reference C<sub>sense</sub>. The circuit of figure 15 is also applicable to other applications, such as a fingerprint sensor and a DNA sensor.

[0050] Figure 16 illustrates the application of the driver circuit of the present invention to a night vision camera. In figure 16 a photoconductor is indicated by refrenece R.

**[0051]** In the embodiments illustrated with reference to the above specific description the transistors have been shown as p-channel type transistors. This is not limiting of the invention. For example, figure 17 is a brief outline of an alternative implementation of the circuit of figure 4. In figure 17 n-channel transistors are used throughout the circuit, except for the drive transistor which is retained as a p-channel transistor.

[0052] It will be apparent to persons skilled in the art that other variations and modifications can be made to the arrangements described with respect to figures 3 to 16 without departing from the scope of the invention.

#### Claims

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- 1. A driver circuit operating in stages that comprise a programming stage and a reproduction stage, the circuit comprising: a plurality of current paths each of which passes through the circuit, a current driven element, a transistor connected so as operatively to control the current supplied to the said element, a capacitor connected for storing an operating voltage of the transistor during the programming stage, and switching means which control the current paths, the arrangement being such that one of the current paths does not include the said element.
- A driver circuit for driving a pixel of an electroluminescent device, the pixel including an electroluminescent element and the circuit comprising; a transistor connected so as operatively to control the current supplied to the electroluminescent element, a capacitor connected for storing an operating voltage of the transistor during a programming stage, a first switching means connected so as to establish when operative a current path through the transistor during the programming stage, and a second switching means connected so as to establish when operative a current path through the transistor and the electroluminescent element during a reproduction stage, wherein the first switching means is connected such that the current path during the programming stage does not pass through the electroluminescent element.

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- 3. A driver circuit for driving a pixel of an electroluminescent device, the pixel including an electroluminescent element and the circuit comprising; a transistor connected so as operatively to control the current supplied to the electroluminescent element, a capacitor connected for storing an operating voltage of the transistor during a programming stage, a first switching means connected so as to establish when operative a current path through the transistor during the programming stage, a second switching means connected so as to establish when operative a current path through the transistor and the electroluminescent element during a reproduction stage, and a current sink, the first switching means being connected such that the current path during the programming stage is through the transistor to the current sink.
- **4.** A driver circuit as claimed in claim 2 or 3, wherein the first and second switching means are controlled by respective control signals separate from each other.
- 5. A driver circuit as claimed in any of claims 1 to 4, further comprising a third switching means, the third switching means being connected to bias the transistor to act as a diode during the programming stage.
- 6. A driver circuit as claimed in claim 5, wherein the third switching means connects the first switching means to the source/drain current path of the transistor.
- 7. A driver circuit as claimed in claim 5, wherein the third switching means connects the first switching means to the gate of the transistor.
- 8. A driver circuit as claimed in any of claims 2 to 7, wherein an additional transistor is connected in parallel with the said transistor, an additional switching means interconnects the drains of the transistors, and the gate of the additional transistor is connected to the gate of the said transistor.
- 9. A driver circuit as claimed in claim 8, comprising a plurality of additional transistors each with a respective additional switching means, each additional transistor and additional switching means being connected as aforesaid with the additional switching means being connected in series with each other.
- **10.** A driver circuit as claimed in any preceding claim, wherein the circuit is implemented with polysilicon thin film transistors.
- 11. A method of controlling the current supply to an

- electroluminescent element comprising the steps of providing a current path during a programming stage which path does not pass through the electroluminescent element and of providing a current path during a reproduction stage which path does pass through the electroluminescent element.
- 12. A method of controlling the current supply to an electroluminescent element comprising the steps of providing a current path during a programming stage which path connects to a current sink and of providing a current path during a reproduction stage which path passes through the electroluminescent element.
- 13. An electroluminescent display device comprising one or more driver circuits as claimed in any of claims 1 to 10.
- 10 14. An electronic apparatus incorporating an electroluminescent display device as claimed in claim 13.
  - **15.** A driver circuit as claimed in claim 5, wherein the third switching means is disposed between the capacitor and the first switching means.
  - **16.** A driver circuit as claimed in any of claims 1 to 10, wherein the said transistor is a p-channel thin film transistor
  - **17.** A driver circuit as claimed in claim 5, wherein the first, the second, and the third sitching means are formed of respective n-channel thin film transistors.
- 18. A circuit comprising a current driven element, the circuit providing a first current path including the current driven element and a second current path not including the current driven element.
- 40 19. A circuit comprising a current driven element, the circuit providing a first current path flowing a current through the current driven element, and a second current path not flowing current through the current driven element.
  - 20. The circuit according to claim 18 or claim 19, further comprising a transistor for controlling a current supplied to the current driven element.
  - 21. The circuit according to claim 20, wherein the second current path is disposed so that the second current path is enabled to be connected to a power source.
- 22. The circuit according to claim 20, wherein the second current path further includes a first switching means.

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- 23. The circuit according to claim 20, wherein the second current path includes at least one of the transistor and another transistor that determines a current flowing throught the transistor.
- **24.** The circuit according to claim 20, further comprising a capacitor connected to a gate of the transistor.
- **25.** The circuit according to claim 24, further comprising a second switching means disposed between the current driven element and the transistor.
- **26.** The circuit according to claim 25, further comprising a third switching means disposed between the first switching means and the capacitor.
- 27. The circuit according to claim 25, wherein the first switching means and the second switching means are controlled by respective control signals separated from each other.
- **28.** The circuit according to claim 18 or claim 19, wherein the current driven element is an organic electroluminescent element.
- **29.** The circuit according to claim 20, wherein the transistor is a p-channel thin film transistor.
- **30.** The circuit according to claim 26, wherein the first, the second, and the third switching means are n-channel thin film transistors.
- **31.** The circuit according to claim 20, wherein the first current path and the second current path including the transistor
- 32. An electro-optical device having a plurality of pixels and at least one pixel comprising a circuit with a current driven element and a current determining means for determining a current according to a data signal, the circuit providing a first current path including the current driven element and a second current path not including the current driven element.
- **33.** An electronic apparatus including the electro-optical device according to claim 32.
- 34. The circuit according to claim 18 or claim 19, wherein the second current path is connected to a current 50 sink
- 35. The circuit according to claim 21, wherein the second current path is connected to a current sink.
- **36.** A method for driving a circuit comprising a current driven element and a transistor that controls a current supplied to the current driven element, com-

- prising a step of determining a gate voltage of the transistor based on a predetermined current.
- **37.** The method according to claim 36, further comprising a step of supplying a current to the current driven element.
- 38. The method according to claim 36, wherein no current is supplied to the current driven element during the step of determining a gate voltage of the transistor based on a predetermined current.

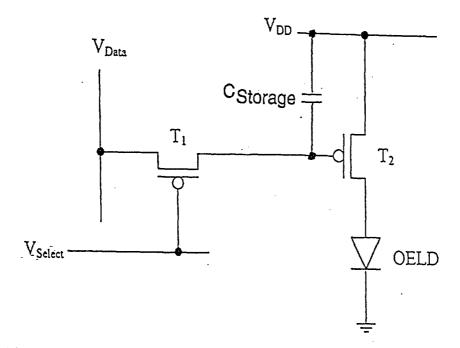


Figure 1

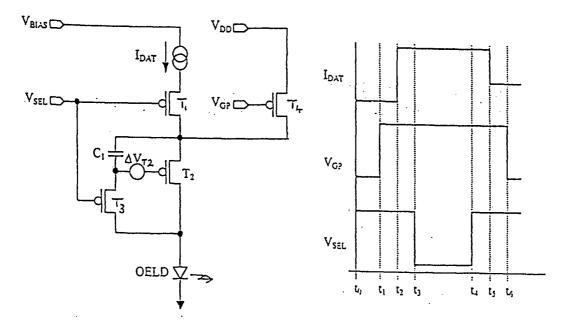


Figure 2

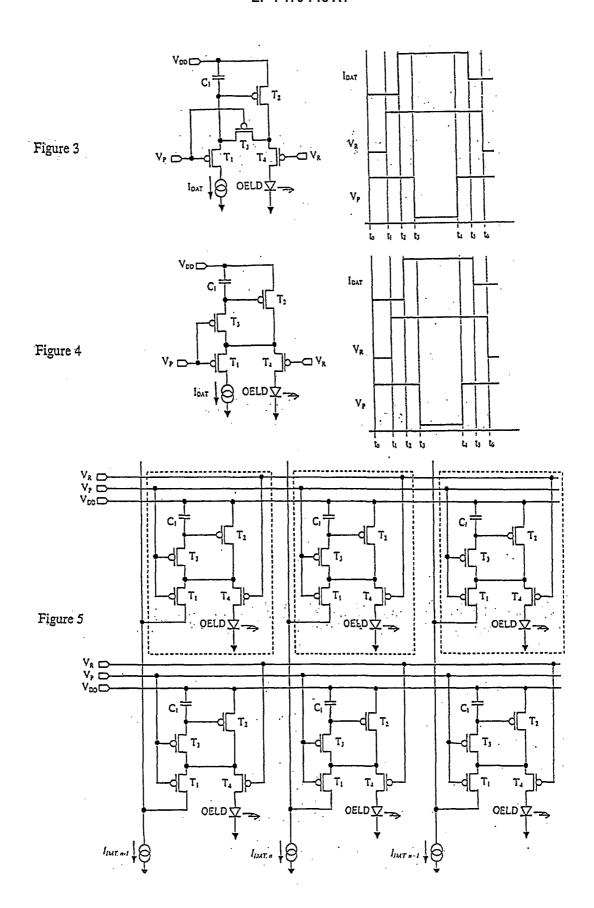
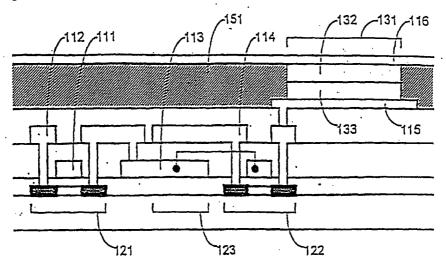
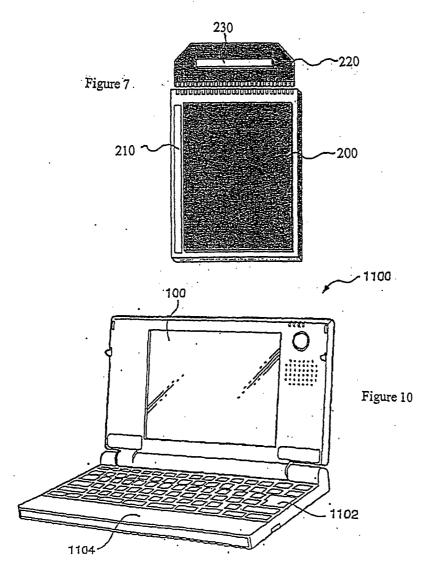
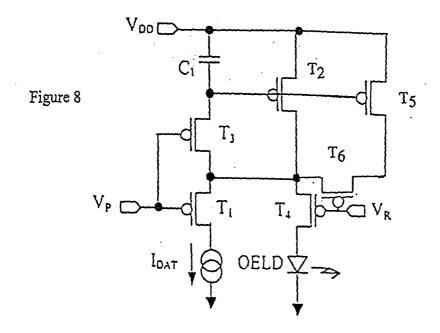
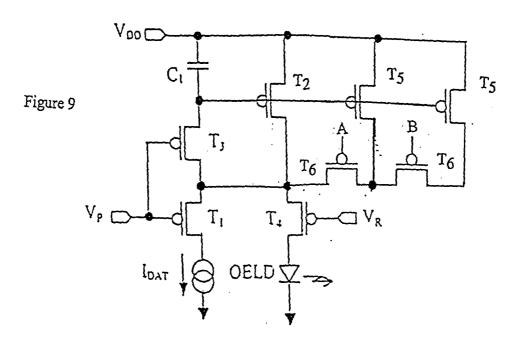


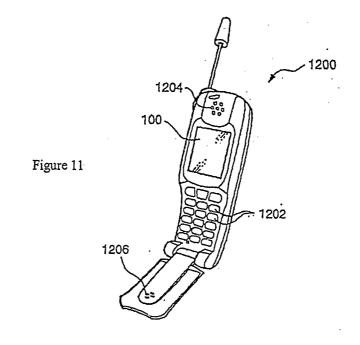
Figure 6

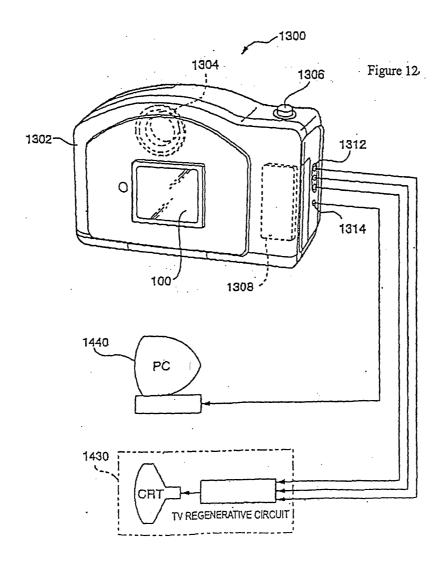


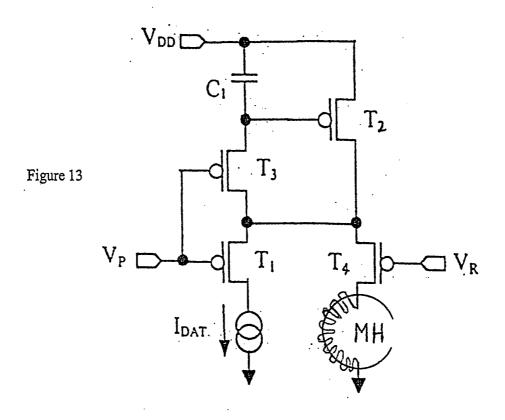


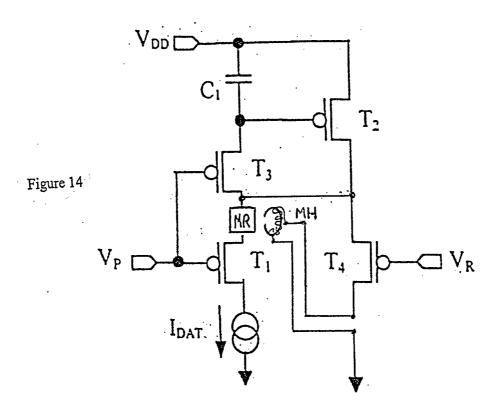


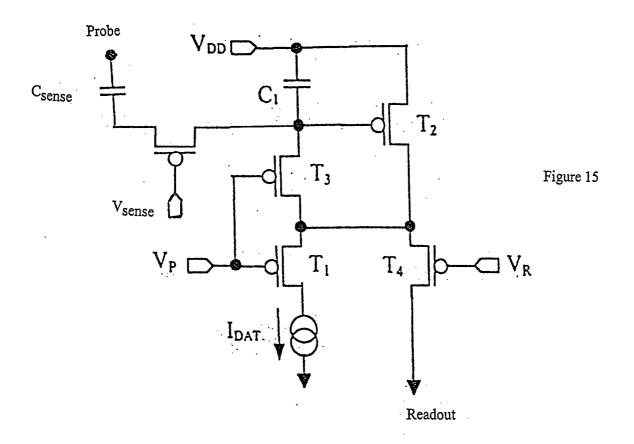


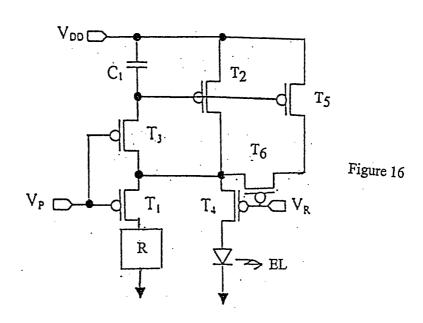


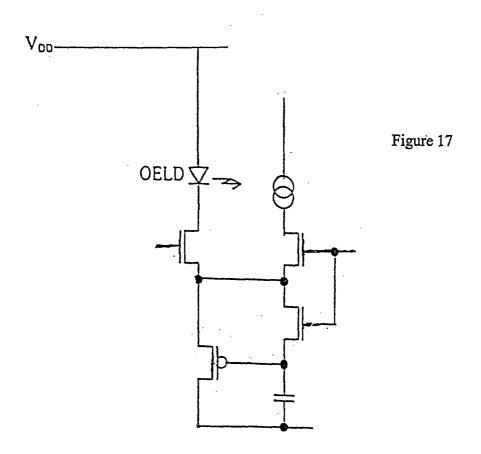














# **EUROPEAN SEARCH REPORT**

Application Number

EP 01 30 5898

Category	Citation of document with indica of relevant passages		Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.CI.7)
X	WO 99 65011 A (KONINKL NV ; PHILIPS SVENSKA AE 16 December 1999 (1999 * page 8, line 12 - pa * page 14, line 26 - p	PHILIPS ELECTRONICS (SE)) -12-16) uge 13, line 27 *		G09G3/32 G11C27/02
A	JP 11 282419 A (NEC CC 15 October 1999 (1999- -& US 6 091 203 A (SAS 18 July 2000 (2000-07- * column 7, line 33 - * column 12, line 1 -	-10-15) AKI HIROSHI ET AL) -18) column 8, line 27 *	8,9	
				TECHNICAL FIELDS SEARCHED (Int.Cl.7)
<del></del>	The present search report has been	drawn up for all claims		
	Place of search THE HAGUE	Date of completion of the search 31 October 2001	Ami	Examiner
X : parti Y : parti docu	ATEGORY OF CITED DOCUMENTS  cularly relevant if taken alone cularly relevant if combined with another ment of the same category nological background	T: theory or principl E: earlier patent do after the filing da D: document cited i L: document cited if	e underlying the i cument, but publi te n the application or other reasons	an, D nvention shed on, or

# ANNEX TO THE EUROPEAN SEARCH REPORT ON EUROPEAN PATENT APPLICATION NO.

EP 01 30 5898

This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report. The members are as contained in the European Patent Office EDP file on The European Patent Office is in no way liable for these particulars which are merely given for the purpose of information.

31-10-2001

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For more details about this annex : see Official Journal of the European Patent Office, No. 12/82



专利名称(译)	用于有机电致发光显示器的电流采样电路					
公开(公告)号	EP1170718A1	公开(公告)日	2002-01-09			
申请号	EP2001305898	申请日	2001-07-09			
[标]申请(专利权)人(译)	精工爱普生株式会社					
申请(专利权)人(译)	SEIKO EPSON CORPORATION					
当前申请(专利权)人(译)	SEIKO EPSON CORPORATION					
[标]发明人	TAM SIMON					
发明人	TAM, SIMON					
IPC分类号	G09G3/32 G11C27/02					
CPC分类号	G09G3/325 G09G2300/0842 G09G2300/0861 G09G2320/0252 G11C27/024					
代理机构(译)	斯特,CLIFFORD MARK					
优先权	2000016816 2000-07-07 GB					
其他公开文献	EP1170718B1					
外部链接	Espacenet					

# 摘要(译)

1。一种驱动电路,其包括编程级和再现级,所述电路包括:多个电流路径,每个电流路径穿过所述电路;电流驱动元件;晶体管,其连接成可操作地控制提供给所述电流源的电流;所述元件,连接用于在编程阶段期间存储晶体管的工作电压的电容器,以及控制电流路径的开关装置,其中一个电流路径不包括所述元件。在编程阶段期间没有电流由电流控制晶体管施加到电流驱动元件,因此降低了总功耗。此外,电路可以从正常电源电压操作,而不需要高偏置电压。在编程阶段期间,电路使用电流阱而不是电流源。优选地,电流驱动元件是电致发光元件。

